



# Fluorescence and Raman studies of micro-machined glasses exposed to femtosecond pulses at variable repetition rate





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GOMD/ISNOG 2004, Cape Canaveral, FL



# Fs laser micromachining



#### **Difference in low and high rep rate behavior**





# **Difference in low and high rep rate behavior**









- Fluorescence: modified regions contian NBOHC defects annealing of defects under 488 nm cw light
- Raman: modified regions have higher concentrations of 3- and 4-membered rings → increase in density and refractive index

Chan et al Optics Letters, **26**, 1726 (2001). Chan et al. Applied Physics A**76**, 367 (2003).



## glasses and writing conditions



	amplified Ti-Sa laser 0.4 NA objective		Ti-Sa oscillator 1.4 NA objective
sample	fused silica	borosilicate (Corning 2947)	
pulse energy	1-3.5 µJ	1-3.5 µJ	6 nJ
rep rate	10-250 KHz	10-250 KHz	25 MHz
scan speed	4-400 µm/s	4-400 µm/s	40-40,000 µm/s



#### **Fused silica - low rep rate**







excitation with 488 nm light



Chan *et. al*, Appl. Phys. A76, 367 (2003) Sun *et. al*, J. Phys. Chem. B, 104, 3450 (2000)

Denise Krol 11/09/04



#### **Total fluorescence intensity in fused silica**







#### **Borosilicate glass - low rep rate**



# 10 KHz, 400 $\mu$ m/s 250 KHz, 400 $\mu$ m/s 10 KHz, 4 μm/s 250 KHz, 4 mm/s



3.5 μJ

1 *µ*J





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#### Fluorescence in borosilicate glass









## Fluorescence in borosilicate glass





#### borosilicate glass- high rep rate



#### 40,000 µm/s



#### **10** μ**m**

#### 4000 µm/s



#### 400 µm/s



#### 40 µm/s



Fluorescence in borosilicate glass-high rep rate

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#### Summary



□ Fluorescence experiments show that NBOHC are formed as a results of fs laser exposure in fused silica and borosilicate glass

Defects are formed at both low and high laser rep rate

□ The defect concentration increases with increase of fs dose possible annealing of defects at very high dose

Still to do:

Characterization of overall network structure of modified lines using Raman spectroscopy

Probe for spatial variations of fluorescence across lines in high rep rate (cumulative) regime





excitation with 15 mW 488 nm light





scan sample with focused 488 nm beam (100x objective) yields x-y spatial profile of color centers



# The 490 cm<sup>-1</sup> and 605 cm<sup>-1</sup> peaks in the Raman spectra increase with fs pulse energy

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Increase in peak area saturates to a maximum of ~5 times the original area